

## **Phase Control Thyristors** (Stud Version), 280 A



PRODUCT SUMMARY			
I <sub>T(AV)</sub>	280 A		
V <sub>DRM</sub> /V <sub>RRM</sub>	400 V, 600 V		
$V_{TM}$	1.28 V		
I <sub>GT</sub>	150 mA		
T <sub>J</sub>	-40 °C to +125 °C		
Package	TO-93 (TO-209AB)		
Circuit configuration	Single SCR		

#### **FEATURES**





- International standard case TO-93 (TO-209AB)
- · Hermetic metal case with glass-metal seal insulator
- · Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
1		280	A	
I <sub>T(AV)</sub>	T <sub>C</sub>	85	°C	
I <sub>T(RMS)</sub>		440		
I <sub>TSM</sub>	50 Hz	7850	A	
	60 Hz	8220		
12.	50 Hz	308	kA <sup>2</sup> s	
l <sup>2</sup> t	60 Hz	281	- KA-S	
V <sub>DRM</sub> /V <sub>RRM</sub>		400/600	V	
tq	Typical	100	μs	
T <sub>J</sub>		-40 to +125	°C	

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS							
TYPE NUMBER	MBER VOLTAGE CODE VDRM/VRRM, MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V		V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA			
VS-ST280S	04	400	500	30			
V3-312003	06	600	700	50			



ABSOLUTE MAXIMUM RATINGS	3					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	1	180° condu	ction, half sine v	wave	280	Α
at case temperature	I <sub>T(AV)</sub>				85	°C
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 75 °C	case temperat	ure	440	
		t = 10 ms	No voltage		7850	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		8220	A kA <sup>2</sup> s
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	Sinusoidal half wave, initial $T_J = T_J$ maximum	6600	
		t = 8.3 ms	reapplied		6900	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 10 ms	No voltage		310	
		t = 8.3 ms	reapplied		220	
		t = 10 ms	100 % V <sub>RRM</sub>		218	
		t = 8.3 ms	reapplied		200	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied		3100	kA²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$ ), $T_J = T_J$ maximum	0.84	V
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.88	V
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		0.50	<b></b> .	
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.47	mΩ	
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 880 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$		1.28	V	
Maximum holding current	I <sub>H</sub>	T 05.00		600	A	
Maximum (typical) latching current	ΙL	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load			1000 (300)	mA

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs		
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}, T_J = 25 °C$	1.0			
Typical turn-off time	t <sub>q</sub>	$I_{TM}$ = 300 A, $T_J$ = $T_J$ maximum, $dI/dt$ = 20 A/ $\mu$ s, $V_R$ = 50 V, $dV/dt$ = 20 V/ $\mu$ s, gate 0 V 100 $\Omega$ , $t_p$ = 500 $\mu$ s	100	μs		

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNIT S			
Maximum critical rate of rise of off-state voltage	dV/dt	T <sub>J</sub> = T <sub>J</sub> maximum linear to 80 % rated V <sub>DRM</sub>	500	V/µs			
Maximum peak reverse and off-state leakage current	I <sub>RRM,</sub> I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	30	mA			



TRIGGERING						
PARAMETER	SYMBOL		TTOT COMPLETIONS		VALUES	
PARAMETER	STIVIBUL	TEST CONDITIONS		TYP.	MAX.	S
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum,	, t <sub>p</sub> ≤ 5 ms	10	0.0	W
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	, f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	, t <sub>p</sub> ≤ 5 ms	3	.0	Α
Maximum peak positive gate voltage	+ V <sub>GM</sub>	T - T maximum	+ < 5 mg	2	.0	V
Maximum peak negative gate voltage	- V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms		5.0		] v
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Maximum required gate trigger/current/voltage are the lowest value which will	180	-	mA
DC gate current required to trigger		T <sub>J</sub> = 25 °C		90	150	
		T <sub>J</sub> = 125 °C		40	-	
		T <sub>J</sub> = - 40 °C	trigger all units 12 V anode to cathode	2.9	1	
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	applied	1.8	3.0	V
		T <sub>J</sub> = 125 °C			-	1
DC gate current not to trigger	I <sub>GD</sub>	T T. movimum	Maximum gate current/voltage not to trigger is the maximum value which will			mA
DC gate voltage not to trigger	$V_{GD}$	T <sub>J</sub> = T <sub>J</sub> maximum not trigger any unit with rated anode to cathode applied		0.	25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	TJ		-40 to +125	°C	
Maximum storage temperature range	T <sub>Stg</sub>		-40 to +150	30	
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation	0.105 K/W		
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.04		
Maunting targue + 10 0/		Non-lubricated threads	31 (275)	N·m	
Mounting torque, ± 10 %		Lubricated threads	24.5 (210)	(lbf · in)	
Approximate weight			280	g	
Case style		See dimensions - link at the end of datasheet	TO-93 (TO-	209AB)	

△R <sub>thJC</sub> CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.016	0.012				
120°	0.019	0.020				
90°	0.025	0.027	$T_J = T_J$ maximum	K/W		
60°	0.036	0.037				
30°	0.060	0.060				

#### Note

• The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC



#### www.vishay.com

## Vishay Semiconductors

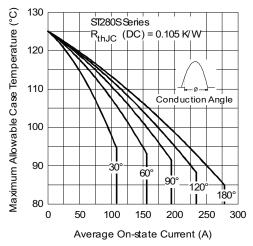


Fig. 1 - Current Ratings Characteristics

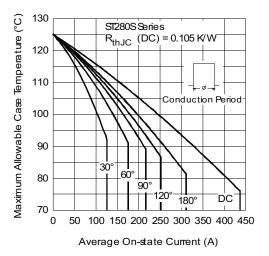


Fig. 2 - Current Ratings Characteristics

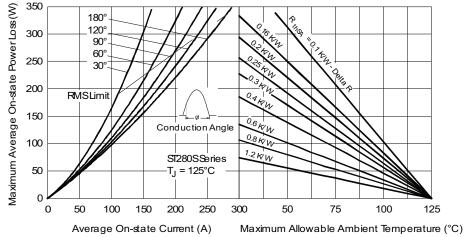


Fig. 3 - On-State Power Loss Characteristics

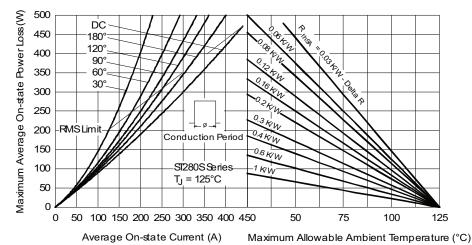


Fig. 4 - On-State Power Loss Characteristics



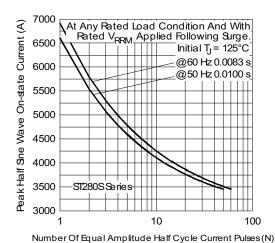
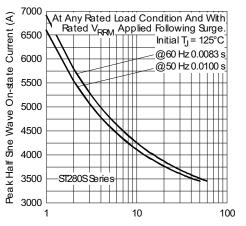


Fig. 5 - Maximum Non-Repetitive Surge Current



Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 6 - Maximum Non-Repetitive Surge Current

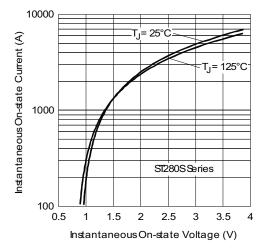


Fig. 7 - On-State Voltage Drop Characteristics

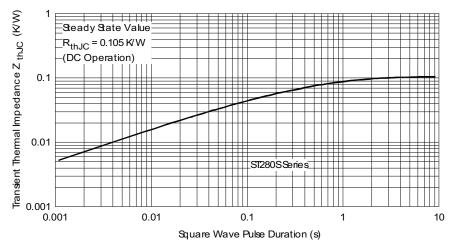


Fig. 8 - Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

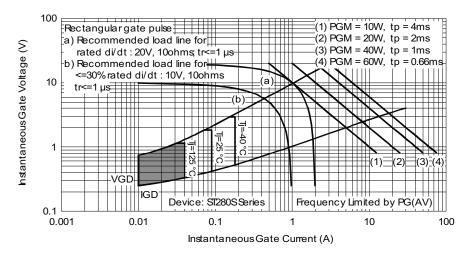
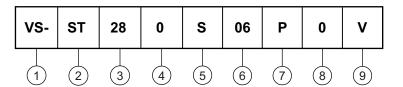


Fig. 9 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



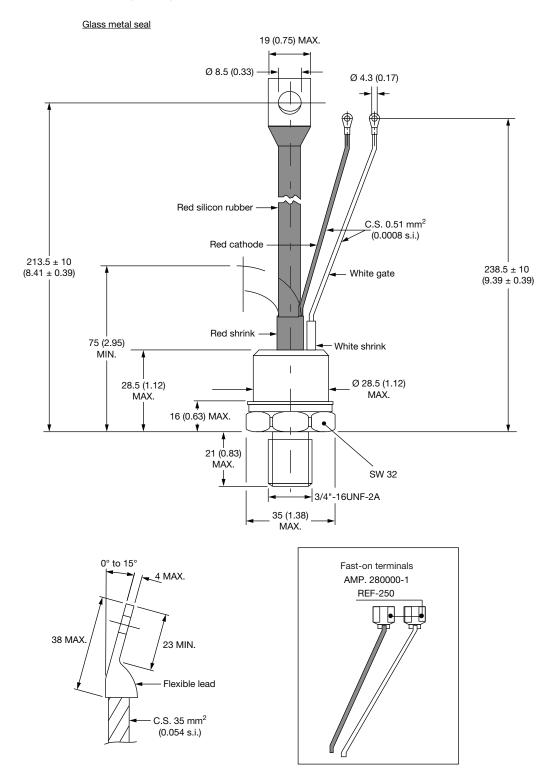
- 1 Vishay Semiconductors product
- 2 Thyristor
- 3 Essential part number
- 4 0 = converter grade
- 5 S = compression bonding stud
- 6 Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)
- 7 P = stud base 3/4"-16UNF-2A threads
- 8 0 = eyelet terminals (gate and auxiliary cathode leads)
  - 1 = fast-on terminals (gate and auxiliary cathode leads)
- 9 V = glass-metal seal

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95077	



# TO-209AB (TO-93)

### **DIMENSIONS** in millimeters (inches)





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